

Description

The S2269SC is a highly integrated current mode PWM controller IC for those high output power of off line flyback convertor. The output power is up to 120W.

S2269SC is integrated start-up circuit that realizes low quiescent dissipation and overload compensation.

S2269SC has comprehensive protection feature to ensure reliability of application system. The packaging of S2269SC has SOP8 and DIP8.

Features

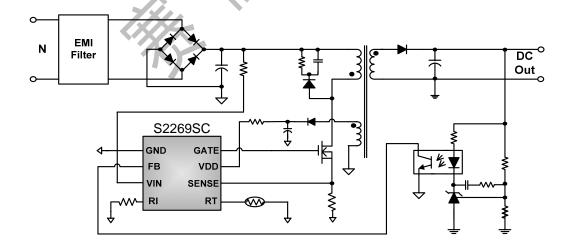
- Digit frequency shuffling technology to improve EMI performance.
- External programmable PWM switching frequency.
- Leading edge Blanking on current sense input.
- Internal synchronized slope compensation .
- Burst mode control to improve efficiency and optimize standby power consumption.

- Low start-up current and low operating current.
- Comprehensive protection functions
 - 1. Under voltage locked with hysteresis (UVLO) on VDD
 - 2. Over voltage protection (OVP) on VDD.
 - 3. Cycle-by-Cycle current limitation
 - 4. Over load protection (OLP)
 - 5. Over temperature protection(OTP)
- Current limitation compensation to obtain the same output current in universal AC line input.
- 800mA Drive Capability

Applications

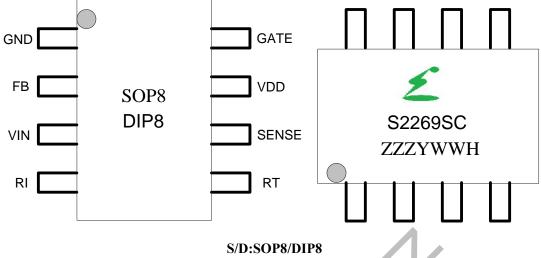
- Digital Cameras Charger
- Power adaptor
- Battery charger

Application Circuit



Notice: To ensure the reliability of system, R1 resistance is recommended to be 33 ohms.

Pin Assignment & Marking Information



S/D:SOP8/DIP8
ZZZ:LOT CODE

X:year code (2020=A,2021=B...)

WW:week code (01-52)

H:FAB CODE

Ordering Information

Part number	Package	MOQ
S2269SC	SOP-8	4000pcs
S2269DC	DIP-8	2000pcs

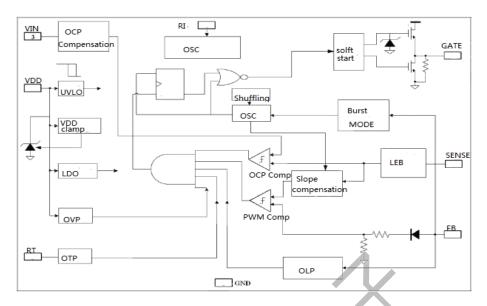
Pin Description

Pin Number	Symbol	Type	Description	
1	GND	P	Ground.	
2	FB	I	Feedback input pin.	
3	VIN	I	Start-up and overload compensation current input pin	
4	RI	I/O	Internal oscillator frequency setting pin.	
5	RT	I/O	Temperature sensing input pin,connected through a NTC resistor to	
6	SENSE	I	Current sense input pin.	
7	VDD	P	Chip DC power supply pin.	
8	GATE	О	Totem-pole gate diver.	

Recommended Out Power

Produc	t	Input:230VAC±15%	Input:85-264VAC	
Troduct		Adapter	Adapter	
S2269S	9SC 120W		90W	

Block Diagram



Absolute Maximum Rating

Parameter	Value	Unit
VIN Input voltage	VDD+2	V
VDD clamp voltage	29	V
VDD clamp continuous current	10	mA
FB input voltage	-0.3 to 7	V
SENSE input voltage	-0.3 to 7	V
RT input voltage	-0.3 to 7	V
RI input voltage	-0.3 to 7	V
Operating ambient temperature	-20 to 85	$^{\circ}$
Min/Max operating junction temperature	-55 to 150	$^{\circ}$ C
Thermal resistance, Junction to shell SOP8	190	°C/W
Thermal resistance, Junction to ambient shell	170	°C/W

Note: Stresses above absolute maximum ratings may cause permanents damage to the device. Exposure to absolutely maximum-rated conditions for extended periods may affects device reliability

Recommended Operating Conditions

Symbol	Parameter	Min.	Max.	Unit
VDD	Supply Voltage	8	26	V
T _A	Operating Ambient Temperature	-20	85	$^{\circ}\mathbb{C}$

ESD Information

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
HBM	Human body model on all pins	JEDEC-STD		2		KV
MM	Machine model on all pins	JEDEC-STD		250		V



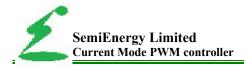
Electrical Characteristics (T_{A} = 25 $^{\circ}$ C without special notation)

	-		Value			Unit
Symbol Symbol	Parameter	Conditions	Min.	Тур.	Max	
	Supply '	Voltage (VDD Pin)	1			
Idd_start-up	VDD start-up current	VDD=12.5V, RI=24K		6	10	uA
Idd	VDD operating current	VDD=18V, RI=24KΩ, FB=3.0V		2. 3		mA
UVLO (enter)	VDD under voltage lockout enter		7. 5	8.3	9	V
UVLO(exit)	VDD under voltage lockout exit	1	13	15	16	V
OVP(enter)	VDD over voltage protection enter		26	31		V
VDD_clamp	VDD clamp voltage	Idd = 10mA	28	33		V
	Voltage	Feedback (FB Pin)	,	,		
AVCS	PWM input gain	Δ VFB / Δ VSENSE		2.8		V/V
VFB_open	open loop voltage			5. 7		V
VFB_burst	Burst mode voltage			1.1		V
IFB_short	FB pin short current	Short FB pin to GND and measure current	0.7	0.85	1	mA
VTH_PL	Power limiting FB threshold voltage			3. 7		V
TD_PL	Power limiting delay time			40		mS
	Curren	t Sense(CS Pin)				
T_blanking	Leading-edge blanking time		150	250	750	nS
ZSENSE_IN	Input impedance			30		KΩ
VTH	Current limitation threshold voltage	I(VIN)= 0 uA duty=0	0.89	0.96	1.03	V
VTH	Current limitation			0.84	0.91	V
	0sci	llator(RI Pin)				
Fosc	Normal oscillation frequency	RI=24K Ω	59	65	71	Khz

S2269SC

V0	02	DataSheet
vu	.92	DataSneer

Δf_temp	Frequency temperature stability	TA-20°C to 100°C VDD=16V, RI=24KΩ		5		%
Δf_VDD Frequency voltage stability		VDD=16.5V to 25V RI=24KΩ		5		%
RI_range	Operating resistor range		12	24	60	ΚΩ
VRI	Voltage of RI to GND	RI=24K Ω		2		V
Fosc_BM	Burst mode base frequency		19	25	40	Khz
DC_MAX	Maximum duty cycle	VDD=18V, FB=3V SENSE=0V		80		%
Δf_OSC	Frequency modulation range /Base frequency		-5		+5	%
	Gate Driv	re Output(GATE Pin)				
VOL	Output low level	VDD=18V, IO=-20mA)		0.3	V
VOH	Output high level	VDD=18V, IO=20mA	11			V
V_Clamp	output clamp voltage level	(QQ)		16		V
T_r	Output rising time	VDD=18V, CL=1nF		110		nS
T_f	Output falling time	VDD=18V, CL=1nF		40		nS
	Over Temperat	ure Protection (RT pin)				
I_RT	Output current of RT pin		50	70	100	uA
V_OTP	OTP threshold voltage		0.8		1.2	V
	Start up and Current 1	imitation compensation (VIN	pin)			
G_VIN	Current limitation compensation gain	Δ IVIN/ Δ VCS		2		mS



Application Information

The S2269SC is a highly integrated current mode PWM controller IC for those high output power of off line flyback convertor. The output power is up to 120W. Its main features are optimized for S2269SC in driving capability, quiescent dissipation, current limitation compensation and low cost and reliability.

Start-up Current and Start-up Control

S2269SC has very low start-up current that is less than 10uA. Therefore, the voltage of VDD could be charged up above UVLO(exit) threshold level quickly. A large value resistor can be used in the start-up circuit to minimize quiescent dissipation. The typical resistance value of resistor is 2M Ohms in start-up circuit of S2269SC. The start-up resistor can be connected with the VIN pin or the capacitor of VDD to provide start-up current.

Operating Current

The Operating current of S2269SC is less than 2.3mA. Therefore, S2269SC can have good efficiency. Frequency

shuffling for EMI improvement

The frequency Shuffling is implemented in S2269SC. The oscillation frequency is modulated with a random source so that the harmonic energy is spread out. The spread spectrum minimizes the conduction EMI and therefore reduces system design challenge.

Burst Mode Operation

At zero load or light load condition, the main power dissipation in a switching mode power supply is from switching on the MOSFET, the core of transformer and the snubber circuit. The magnitude of power dissipation is proportional to the number of switching frequency within certain period. Less switching frequency can reduce the power dissipation. S2269SC adjusts the switching frequency according to the loading condition. From light load to no load, the FB voltage drops. While the FB voltage is less than 1.1V, the gate pin output is disabled and kept low, while the FB voltage is higher than 1.2V, the gate output recovers to normal working mode. To reduce audio noise, the switching frequency will be kept higher than 20KHz in burst mode.

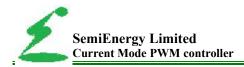
Oscillator Operation

The oscillating frequency of S2269SC is set by the externally resistor between the RI pin and the GND pin. It is recommended that the range of oscillation frequency is in between 20KHz and 100KHz. The relationship between the resistor and the oscillation frequency follows below equation.

$$Fosc = \frac{1625}{RI(K\Omega) + 1}$$
 (KHz)

Current Sensing and Leading-Edge Blanking

Cycle-by-Cycle current limitation is offered in S2269SC. The switching current is detected by a resistor into the



SENSE pin. An internal leading-edge blanking circuit chops off the SENSE voltage spike at initial so that the external RC filtering on SENSE pin is no longer required. The current limiting comparator is disabled and thus cannot turn off the external MOSFET during the blanking period. PWM duty cycle is determined by the voltage in the SENSE pin and the FB pin

Internal Synchronized Slope Compensation

Built-in slope compensation circuit adds voltage ramp onto the current sense input voltage for PWM generation.

This greatly improves the close loop stability at CCM and prevents the sub-harmonic oscillation and thus reduces the output ripple voltage.

Over Temperature Protection

S2269SC is specially optimized for the high output power system. If the temperature from the environment or the component is too high, it results in the system damage. S2269SC provides the function of temperature sensing and the function of over temperature protection. The voltage on the RT pin is determined by resistor between the RT pin and the GND pin. The resistor is usually a NTC resistor. With the Fixed internal current flowing through the resistor, the voltage on the RT pin varies with the resistance value of NTC resistor. When the voltage on the RT pin is higher than 0.8V.

Gate Drive

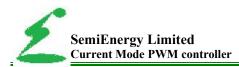
S2269SC Gate pin is used to drive Gate of the external MOSFET. S2269SC has 800mA of sinking and sourcing current that can minimize the switching dissipation of the MOSFET. Therefore, higher efficiency can be obtained. The internally totem pole circuit of the GATE pin can control the MOSFET to be turned on slowly and turned off faster. There is very good compromise between high efficiency and low radiation EMI.

Protection Controls

S2269SC has comprehensive protection functions, including Cycle-by- Cycle current limitation (OCP), Over Load Protection (OLP) and over voltage clamp, Under Voltage Lockout on VDD (UVLO), Over Temperature Protection (OTP).

Current limitation compensation

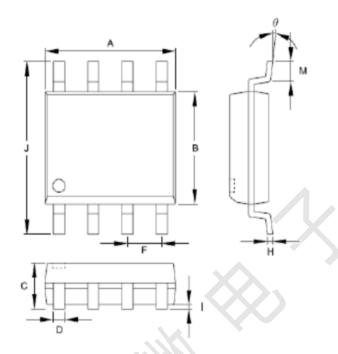
To obtain the same output current capability in the universal AC line voltage range, S2269SC has current limitation compensation. To obtain good current limitation compensation, the start-up



Package Information:

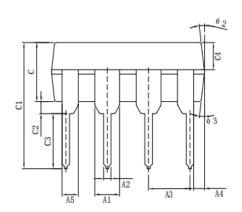
SOP-8

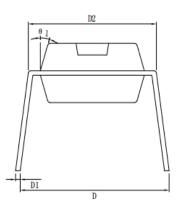
resistor must be connected with the VIN pin.

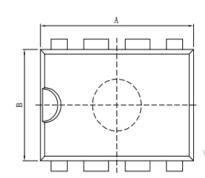


Sumb ala	Dimensions i	n Millimeters	Dimensio	ns in Inch
Symbols	MIN	MAX	MIN	MAX
А	4.801	5.004	0.189	0.197
В	3.810	3.988	0.150	0.157
С	1.346	1.753	0.053	0.069
D	0.330	0.508	0.013	0.020
F	1.194	1.346	0.047	0.053
Н	0.178	0.229	0.007	0.009
I	0.102	0.254	0.004	0.010
J	5.791	6.198	0.228	0.244
М	0.406	1.270	0.016	0.050
θ	0°	8°	0°	8°

DIP-8







Symbol Size	MIN (mm)	MAX (mm)	Size Symbol	MIN (mm)	MAX (mm)
A	9.00	9. 20	C2	0.	50TYP
A1	1. 474	1. 574	C3	3. 20	3. 40
A2	0.41	0.51	C4	1.47	1. 57
A3	2. 44	2. 64	D	8. 20	8.80
A4	0.51	TYP	D1	0. 244	0.264
A5	0.99	TYP	D2	7.62	7. 87
В	6. 10	6.30	θ1	17	° TYP4
С	3. 20	3.40	θ 2	10	° TYP4
C1	7. 10	7. 30	0.3	8°	TYP

Revision History

Version	UPdate date	Version By	Revised content
V0.9	2018-7-14	Li Wen	
V0.91	2019-7-13	Li Wen	OVP ,OCP
V0.92	2021-7-20	Li Wen	